# 3A, 50V - 1000V Surface Mount Rectifier

## FEATURES

TAIWAN

Glass passivated chip junction

EMICONDUCTOR

- Ideal for automated placement
- Low forward voltage drop
- High current capability
- High surge current capability
- Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21

# APPLICATIONS

- Switching mode power supply (SMPS)
- Adapters
- Lighting application
- Converter

# **MECHANICAL DATA**

- Case: DO-214AB (SMC)
- Molding compound meets UL 94V-0 flammability rating
- Part no. with suffix "H" means AEC-Q101 qualified
- Packing code with suffix "G" means green compound (halogen-free)
- Moisture sensitivity level: level 1, per J-STD-020
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Meet JESD 201 class 2 whisker test
- Polarity: As marked
- Weight: 0.21 g (approximately)

KEY PARAMETERS				
PARAMETER	VALUE	UNIT		
I <sub>F(AV)</sub>	3	А		
V <sub>RRM</sub>	50 - 1000	V		
I <sub>FSM</sub>	100	А		
T <sub>J MAX</sub>	150 °C			
Package	DO-214AB (SMC)			
Configuration	Single die			





DO-214AB (SMC)

ABSOLUTE MAXIMUM RATINGS (T <sub>A</sub> = 25°C unless otherwise noted)									
PARAMETER	SYMBOL	S3A	S3B	S3D	S3G	S3J	S3K	S3M	UNIT
Marking code on the device		S3A	S3B	S3D	S3G	S3J	S3K	S3M	
Repetitive peak reverse voltage	V <sub>RRM</sub>	50	100	200	400	600	800	1000	V
Reverse voltage, total rms value	V <sub>R(RMS)</sub>	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	$V_{\text{DC}}$	50 100 200 400 600 800 1000		V					
Forward current	I <sub>F(AV)</sub>	3			А				
Surge peak forward current, 8.3 ms single half sine-wave uperimposed on rated load per diode	I <sub>FSM</sub>	100 A			A				
Junction temperature	TJ	T <sub>J</sub> - 55 to +150 °C				°C			
Storage temperature	T <sub>STG</sub>	T <sub>STG</sub> - 55 to +150 °C				°C			





THERMAL PERFORMANCE			
PARAMETER	SYMBOL	ТҮР	UNIT
Junction-to-lead thermal resistance per diode	R <sub>ejl</sub>	13	°C/W
Junction-to-ambient thermal resistance per diode	R <sub>eja</sub>	47	°C/W

<b>ELECTRICAL SPECIFICATIONS</b> ( $T_A = 25^{\circ}C$ unless otherwise noted)						
PARAMETER	CONDITIONS	SYMBOL	TYP.	MAX.	UNIT	
Forward voltage per diode (1)	I <sub>F</sub> = 3A, T <sub>J</sub> = 25°C	V <sub>F</sub>	-	1.15	V	
$\mathbf{D}$	T <sub>J</sub> = 25°C		-	10	μA	
Reverse current @ rated $V_R$ per diode <sup>(2)</sup>	T <sub>J</sub> = 125°C	- I <sub>R</sub>	-	250	μA	
Junction capacitance	1 MHz, V <sub>R</sub> =4.0V	CJ	60	-	pF	
Reverse recovery time	I <sub>F</sub> =0.5A , I <sub>R</sub> =1.0A I <sub>RR</sub> =0.25A		1500			
	I <sub>RR</sub> =0.25A	t <sub>rr</sub>	1500	-	ns	

#### Notes:

- 1. Pulse test with PW=0.3 ms
- 2. Pulse test with PW=30 ms

DRDERING INFORMATION						
PART NO.	PART NO. SUFFIX	PACKING CODE	PACKING CODE SUFFIX	PACKAGE	PACKING	
		R7		SMC	850 / 7" Plastic reel	
		R6		SMC	3,000 / 13" Paper reel	
S3x (Note 1,2)	н	M6	G	SMC	3,000 / 13" Plastic reel	
(11010 1,2)		V7		Matrix SMC	850 / 7" Plastic reel	
		V6		Matrix SMC	3,000 / 13" Plastic reel	

#### Note :

1. "x" defines voltage from 50V (S3A) to 1000V (S3M)

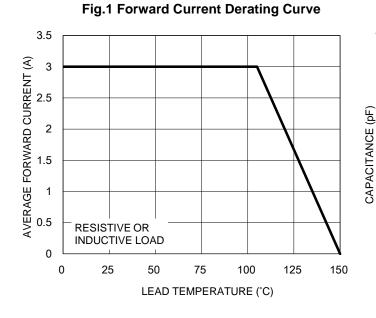
2. Only V6 and V7 are all green compound (halogen free)

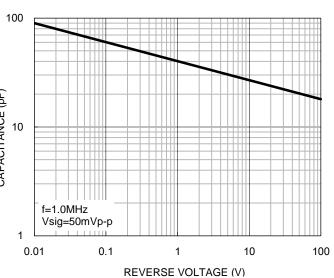
EXAMPLE					
EXAMPLE P/N	PART NO.	PART NO. SUFFIX	PACKING CODE	PACKING CODE SUFFIX	DESCRIPTION
S3AHR7G	S3A	Н	R7	G	AEC-Q101 qualified Green compound



## **CHARACTERISTICS CURVES**

(T<sub>A</sub> = 25°C unless otherwise noted)





**Fig.2 Typical Junction Capacitance** 



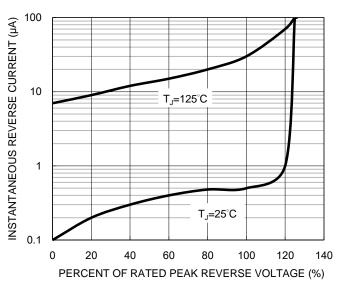
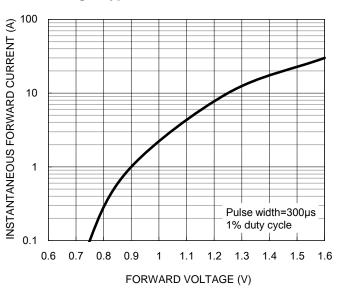


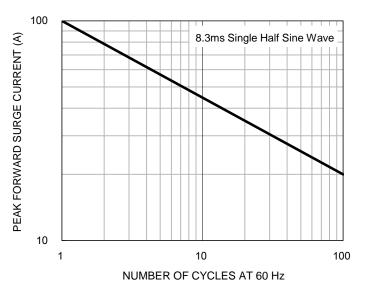
Fig.4 Typical Forward Characteristics





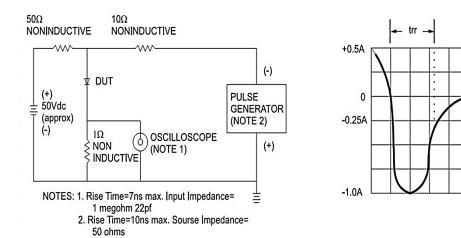
## **CHARACTERISTICS CURVES**

(T<sub>A</sub> = 25°C unless otherwise noted)



### Fig.5 Maximum Non-repetitive Forward Surge Current

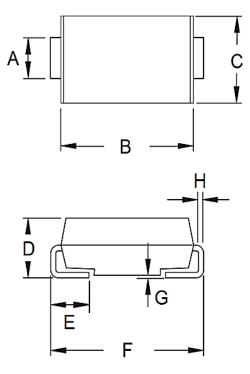






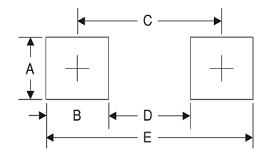
# PACKAGE OUTLINE DIMENSIONS

DO-214AB (SMC)



DIM.	Unit (mm)		Unit (inch)		
DIN.	Min	Max	Min	Max	
А	2.90	3.20	0.114	0.126	
В	6.60	7.11	0.260	0.280	
С	5.59	6.22	0.220	0.245	
D	2.00	2.62	0.079	0.103	
E	1.00	1.60	0.039	0.063	
F	7.75	8.13	0.305	0.320	
G	0.10	0.20	0.004	0.008	
Н	0.15	0.31	0.006	0.012	

# SUGGESTED PAD LAYOUT



Symbol	Unit (mm)	Unit (inch)
А	3.30	0.130
В	2.50	0.098
С	6.80	0.268
D	4.40	0.173
E	9.40	0.370

#### **MARKING DIAGRAM**





- P/N =Marking Code
- G =Green Compound
- YW =Date Code
- F =Factory Code



# Notice

Specifications of the products displayed herein are subject to change without notice. TSC or anyone on its behalf, assumes no responsibility or liability for any errors or inaccuracies.

Information contained herein is intended to provide a product description only. No license, express or implied, to any intellectual property rights is granted by this document. Except as provided in TSC's terms and conditions of sale for such products, TSC assumes no liability whatsoever, and disclaims any express or implied warranty, relating to sale and/or use of TSC products including liability or warranties relating to fitness for a particular purpose, merchantability, or infringement of any patent, copyright, or other intellectual property right.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications. Customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify TSC for any damages resulting from such improper use or sale.

# **X-ON Electronics**

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Rectifiers category:

Click to view products by Taiwan Semiconductor manufacturer:

Other Similar products are found below :

 70HFR40
 RL252-TP
 150KR30A
 1N5397
 NTE5841
 NTE6038
 SCF5000
 1N4002G
 1N4005-TR
 JANS1N6640US
 481235F

 RRE02VS6SGTR
 067907F
 MS306
 70HF40
 T85HFL60S02
 US2JFL-TP
 A1N5404G-G
 CRS04(T5L,TEMQ)
 ACGRA4007-HF

 ACGRB207-HF
 CLH03(TE16L,Q)
 ACGRC307-HF
 ACEFC304-HF
 NTE6356
 NTE6359
 NTE6002
 NTE6023
 NTE6039
 NTE6077

 85HFR60
 40HFR60
 70HF120
 85HFR80
 D126A45C
 SCF7500
 D251N08B
 SCHJ22.5K
 SM100
 SCPA2
 SCH10000
 SDHD5K
 VS 

 12FL100S10
 ACGRA4001-HF
 D1821SH45T PR
 D1251S45T
 NTE5990
 NTE6358
 NTE6162
 NTE5850